TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX244F,TC74LCX244FT,TC74LCX244FK

Low-Voltage Octal Bus Buffer with 5-V Tolerant Inputs and Outputs

The TC74LCX244 is a high-performance CMOS octal bus buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

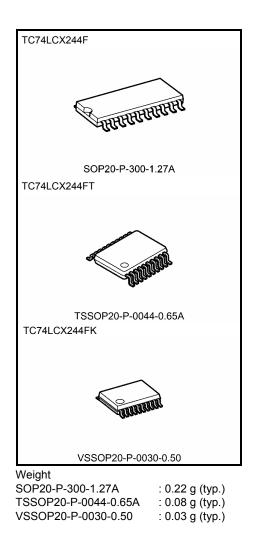
The device is designed for low-voltage $(3.3 \text{ V}) \text{ V}_{CC}$ applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

The 74LCX244F/FT is a non-inverting 3-state buffer having two active-low output enables. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

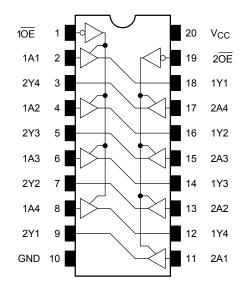
Features

- Low-voltage operation: V_{CC} = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 6.5 \text{ ns} (max) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Ouput current: $|I_{OH}|/I_{OL} = 24 \text{ mA} (\text{min}) (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: -500 mA
- Available in JEITA SOP, TSSOP and VSSOP (US)
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 244 type



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Pin Assignment (top view)



Truth Table

Inp	uts	Outputs
ŌĒ	An	Outputs
L	L	L
L	Н	Н
Н	Х	Z

X: Don't care

Z: High impedance

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	-0.5 to 7.0	V
DC input voltage	VIN	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC output voltage	VOUT	-0.5 to V_{CC} + 0.5	V
		(Note 3)	
Input diode current	I _{IK}	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	–65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

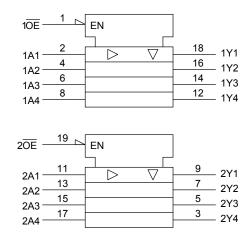
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

IEC Logic Symbol



Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit		
Power supply voltage	2.0 to 3.6		V		
Tower supply voltage	V _{CC}	1.5 to 3.6 (Note 2)	v		
Input voltage	V _{IN}	0 to 5.5	V		
Output voltage	Vout	0 to 5.5 (Note 3)	V		
Output voltage	VOUT	0 to V_{CC} (Note 4)	v		
Output current	Іон/Іог	±24 (Note 5)	mA		
Output current	IOH/IOL	±12 (Note 6)	IIIA		
Operating temperature	T _{opr}	-40 to 85	°C		
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V		

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: $V_{CC}=3.0 \mbox{ to } 3.6 \mbox{ V}$

Note 6: $V_{CC} = 2.7$ to 3.0 V

Note 7: $V_{IN}=0.8$ to 2.0 V, $V_{CC}=3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

Character	istics	Symbol	Test Condition		mbol Test Condition			Min	Мах	Unit
		- ,					-	Unit		
Input voltage	H-level	VIH		_	2.7 to 3.6	2.0	—	V		
input voltage	L-level	VIL		_	2.7 to 3.6	_	0.8	v		
				$I_{OH} = -100 \ \mu A$	2.7 to 3.6	V _{CC} - 0.2	_			
	H-level	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_			
		-		I _{OH} = -18 mA	3.0	2.4	_			
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	v		
			DL $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 12 \text{ m}$ $I_{OL} = 16 \text{ m}$	I _{OL} = 100 μA	I _{OL} = 100 μA	2.7 to 3.6	_	0.2		
	L-level	N		$I_{OL} = 12 \text{ mA}$	2.7	_	0.4			
	L-level	V _{OL} V		OP = AIH OLAIP	$I_{OL} = 16 \text{ mA}$	3.0		0.4	I	
				$I_{OL} = 24 \text{ mA}$	3.0		0.55			
Input leakage currer	nt	l _{IN}	$V_{IN} = 0$ to 5.5 V	·	2.7 to 3.6		±5.0	μA		
	ata aumant		$V_{IN} = V_{IH} \text{ or } V_{IL}$		2.7 to 3.6		15.0			
3-state output off-sta	ale current	loz	V _{OUT} = 0 to 5.5 V		2.7 10 3.0	—	±5.0	μA		
Power off leakage c	urrent	I _{OFF}	$V_{IN}/V_{OUT} = 5.5 V$		0		10.0	μA		
Quiescent supply cu			$V_{IN} = V_{CC}$ or GND		2.7 to 3.6	_	10.0			
		Icc	$V_{IN}/V_{OUT} = 3.6 \text{ to } 5.5 \text{ V}$		2.7 to 3.6	_	±10.0	μA		
Increase in I _{CC} per	input	Δlcc	$V_{IH} = V_{CC} - 0.6$		2.7 to 3.6		500			

AC Characteristics (Ta = -40 to 85° C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	7.5	ns
Topagation delay time	t _{pHL}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	6.5	115
Output enable time	t _{pZL}	Figure 1, Figure 3	2.7	—	9.0	ns
	t _{pZH}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	8.0	
Output disable time	t _{pLZ}	Figure 1, Figure 3	2.7	—	8.0	ns
	t _{pHZ}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	7.0	115
	t _{osLH}	(\$1-4-)	2.7	_	_	ns
Output to output skew	t _{osHL}	(Note)	$\textbf{3.3}\pm\textbf{0.3}$	_	1.0	115

Note: Parameter guaranteed by design. $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5 \text{ ns}$, $C_L = 50 \text{ pF}$, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V_{OL}	VOLP	$V_{IH} = 3.3 V, V_{IL} = 0 V$	3.3	0.8	V
Quiet output minimum dynamic V_{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	—	3.3	7	pF
Output capacitance	C _{OUT}	_	3.3	8	pF
Power dissipation capacitance	CPD	f _{IN} = 10 MHz (Note	3.3	25	pF

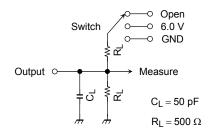
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation: $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per bit)

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AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND



AC Waveform

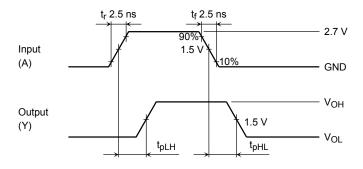


Figure 2 t_{pLH}, t_{pHL}

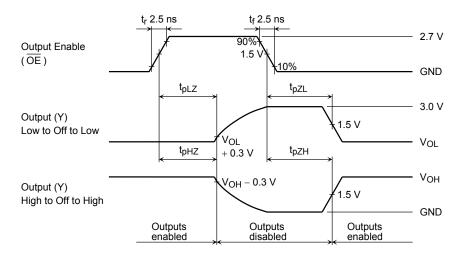
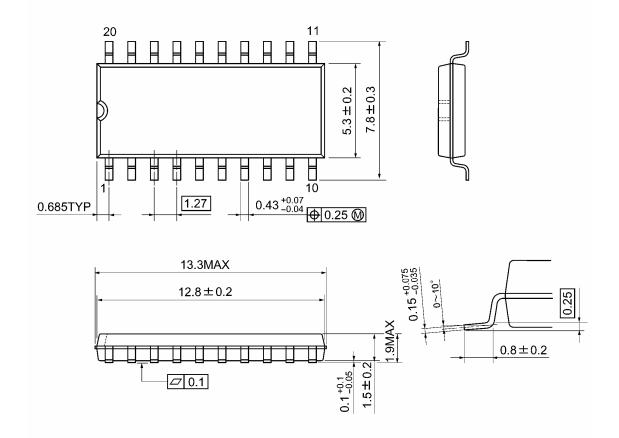


Figure 3 $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$

Package Dimensions

SOP20-P-300-1.27A

Unit: mm



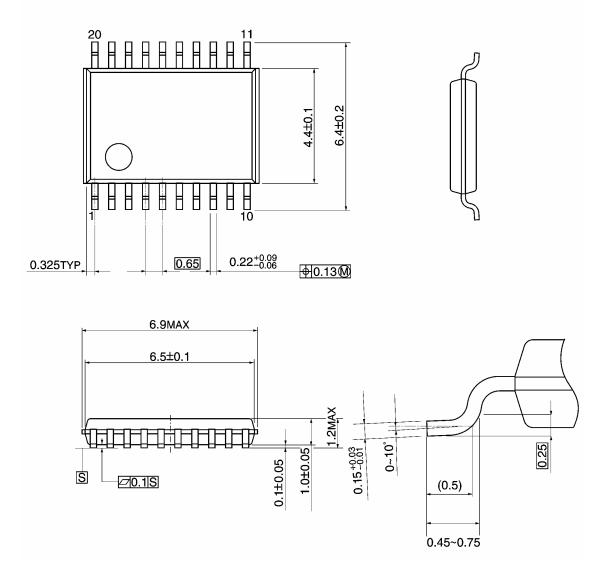
Weight: 0.22 g (typ.)

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Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm



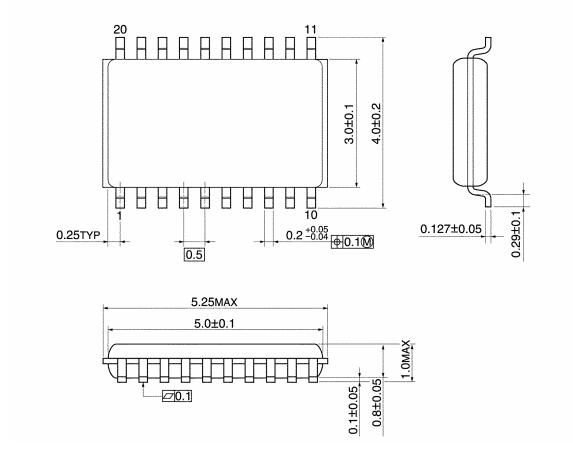
Weight: 0.08 g (typ.)

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Package Dimensions

VSSOP20-P-0030-0.50

Unit: mm



Weight: 0.03 g (typ.)

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